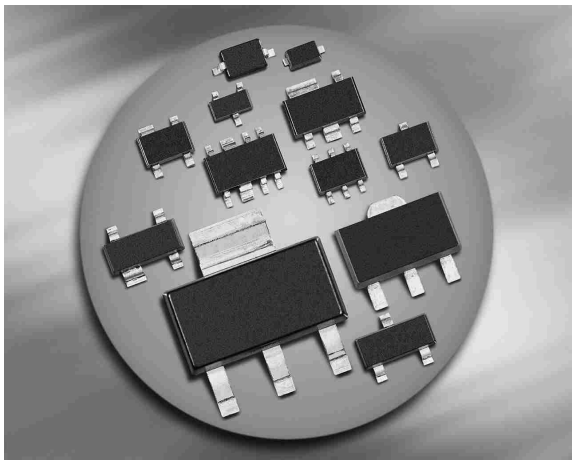
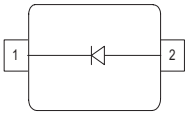
Silicon Schottky Diodes

- Low barrier type for DBS mixer applications up to 12 GHz, phase detectors and modulators
- Low noise figure
- Pb-free (RoHS compliant) package

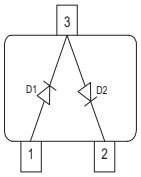
RoHS



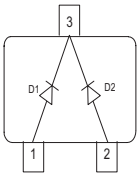
BAT15-02LRH
BAT15-03W



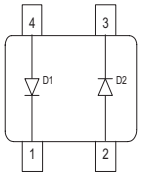
BAT15-04W



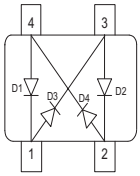
BAT15-05W



BAT15-099
BAT15-099LRH



BAT15-099R



ESD (**E**lectro**s**tatic **d**ischarge) sensitive device, observe handling precaution!

Type	Package	Configuration	L_S(nH)	Marking
BAT15-02LRH	TSLP-2-7	single, leadless	0.4	NP
BAT15-03W	SOD323	single	1.8	white P
BAT15-04W	SOT323	series	1.4	S8s
BAT15-05W	SOT323	common cathode	1.4	S5s
BAT15-07LRH	TSLP-4-7	parallel pair, leadless	0.4	NP
BAT15-098LRH	TSLP-4-7	anti-parallel pair, leadless	0.4	B
BAT15-099	SOT143	anti-parallel pair	2	S5s
BAT15-099R	SOT143	cross-over ring	2	S6s
BAT15-099LRH	TSLP-4-7	anti-parallel pair, leadless	0.4	S5

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	4	V
Forward current	I_F	110	mA
Total power dissipation	P_{tot}		mW
BAT15-02LRH, -099LRH $T_S \leq 76$ °C		100	
BAT15-03W, $T_S \leq 70$ °C		100	
BAT15-04W, $T_S \leq 68$ °C		100	
BAT15-05W, $T_S \leq 65$ °C		100	
BAT15-099, $T_S \leq 48$ °C		100	
BAT15-099R, $T_S \leq 67$ °C		100	
Junction temperature	T_j	150	°C
Operating temperature range	T_{op}	-55 ... 150	
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1)]	R_{thJS}		K/W
BAT15-02LRH, -099LRH		≤ 780	
BAT15-03W		≤ 795	
BAT15-04W		≤ 820	
BAT15-05W		≤ 850	
BAT15-099		≤ 1020	
BAT15-099R		≤ 830	

[1]For calculation of R_{thJA} please refer to Application Note Thermal Resistance

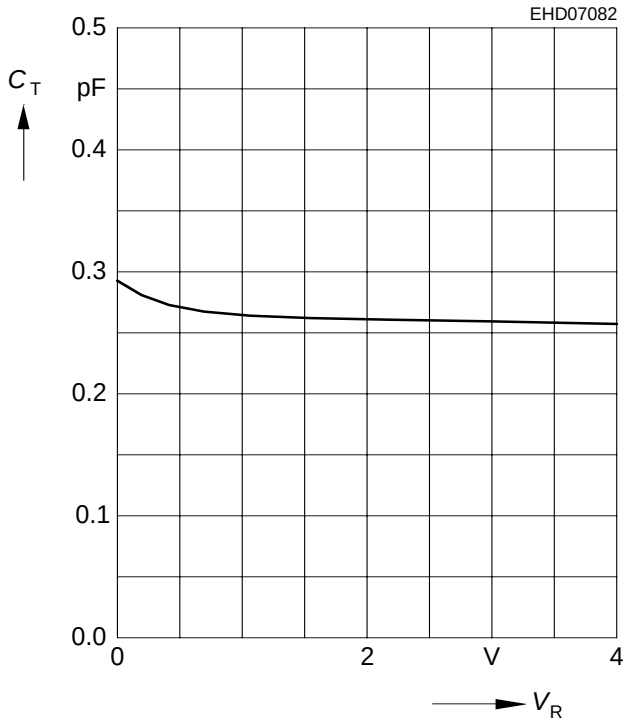
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)}$ = 100 µA	$V_{(BR)}$	4	-	-	V
Forward voltage I_F = 1 mA I_F = 10 mA	V_F	 0.16 0.25	 0.23 0.32	 0.32 0.41	
Forward voltage matching[1)] I_F = 10 mA	ΔV_F	-	-	20	mV
AC Characteristics					
Diode capacitance V_R = 0 V, f = 1 MHz, all other types V_R = 0 V, f = 1 MHz, BAT15-099R	C_T	 - -	 - -	 0.35 0.5	pF
Differential forward resistance I_F = 10 mA / 50 mA	R_F	-	5.5	-	Ω

[1] ΔV_F is the difference between lowest and highest V_F in a multiple diode component.

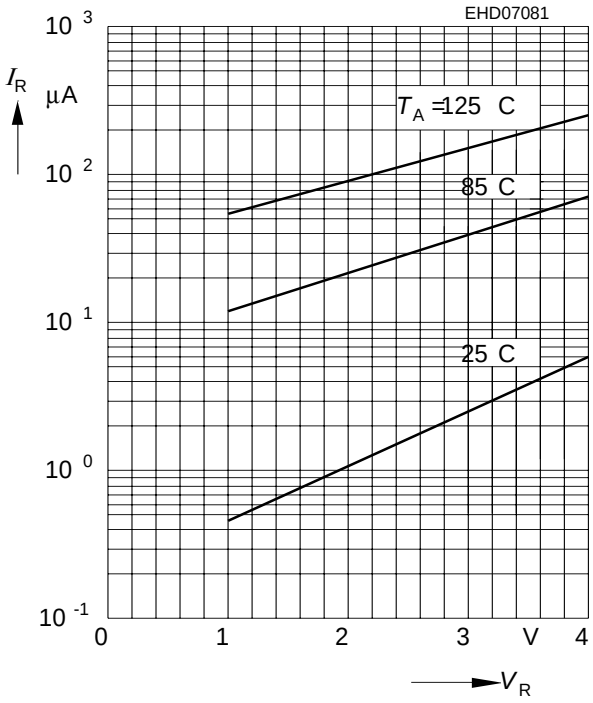
Diode capacitance $C_T = f(V_R)$

f = 1MHz



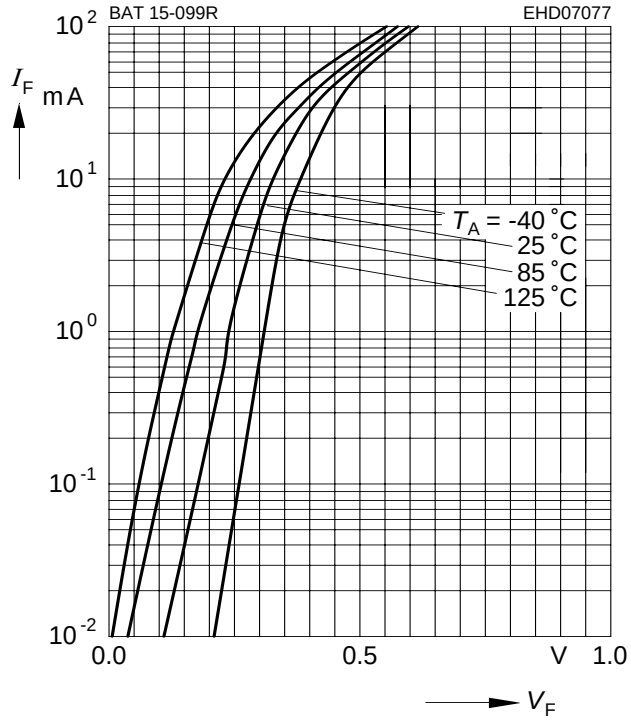
Reverse current $I_R = f(V_R)$

T_A = Parameter



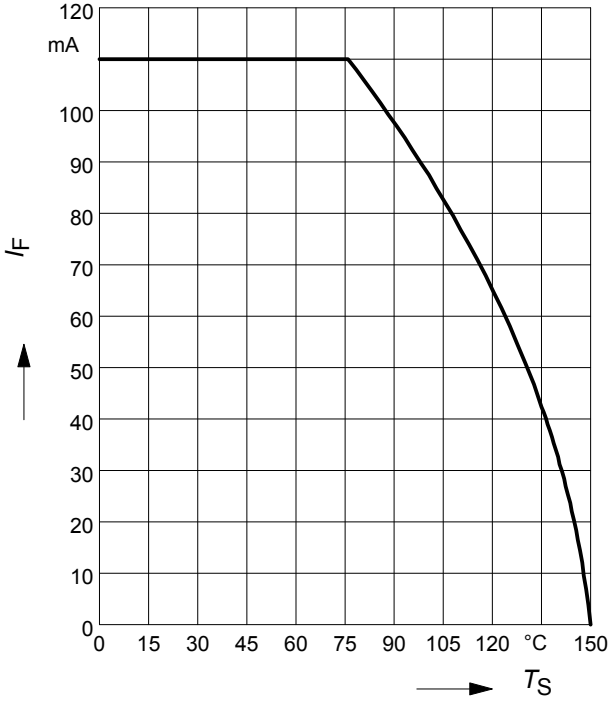
Forward current $I_F = f(V_F)$

T_A = Parameter



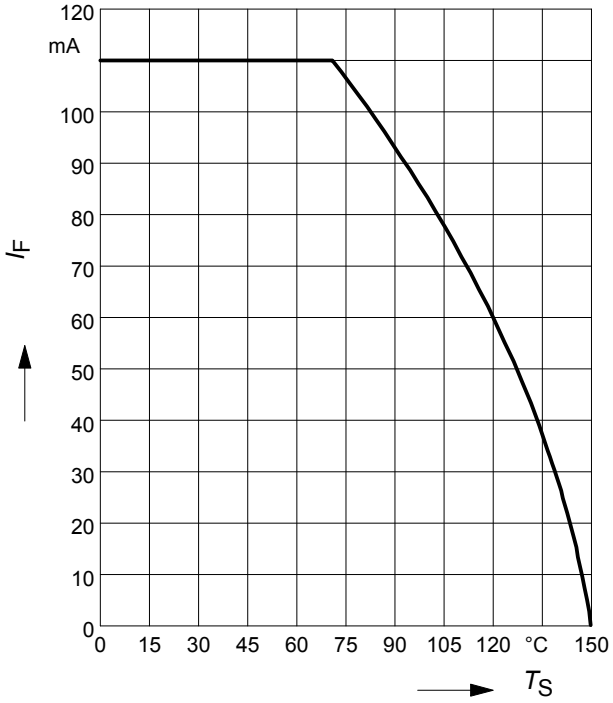
Forward current $I_F = f(T_S)$

BAT15-02LRH, BAT15-099LRH



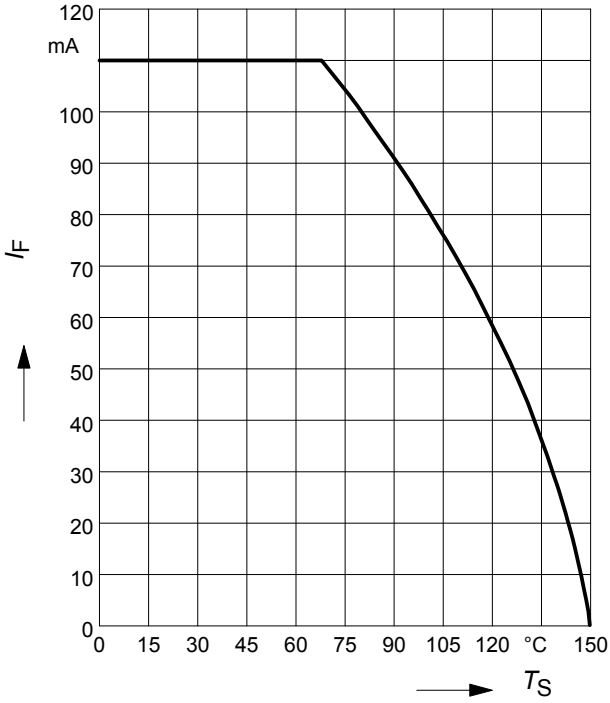
Forward current $I_F = f(T_S)$

BAT15-03W



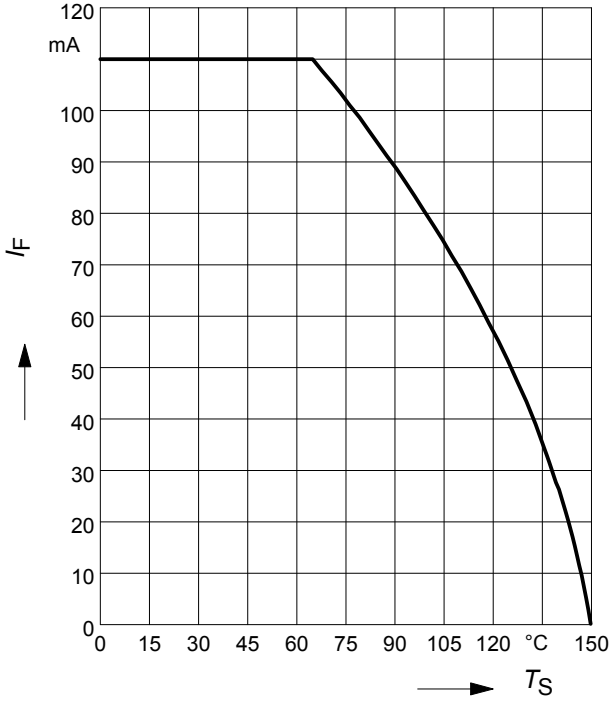
Forward current $I_F = f(T_S)$

BAT15-04W



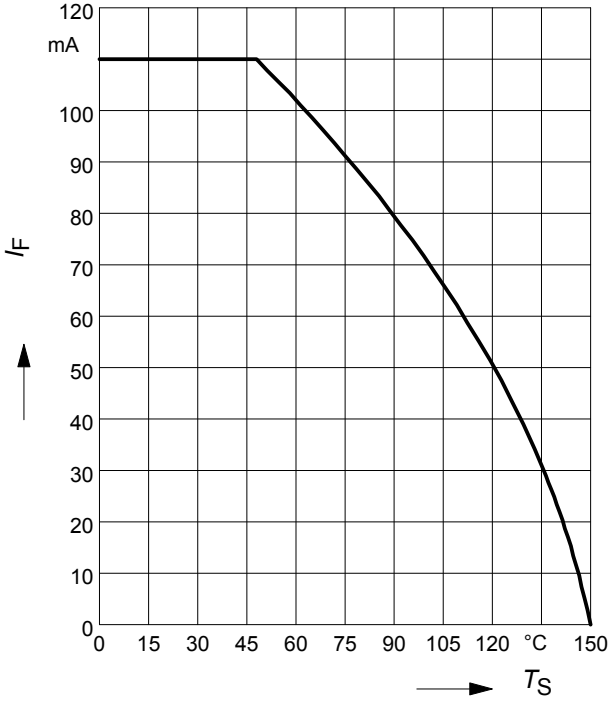
Forward current $I_F = f(T_S)$

BAT15-05W



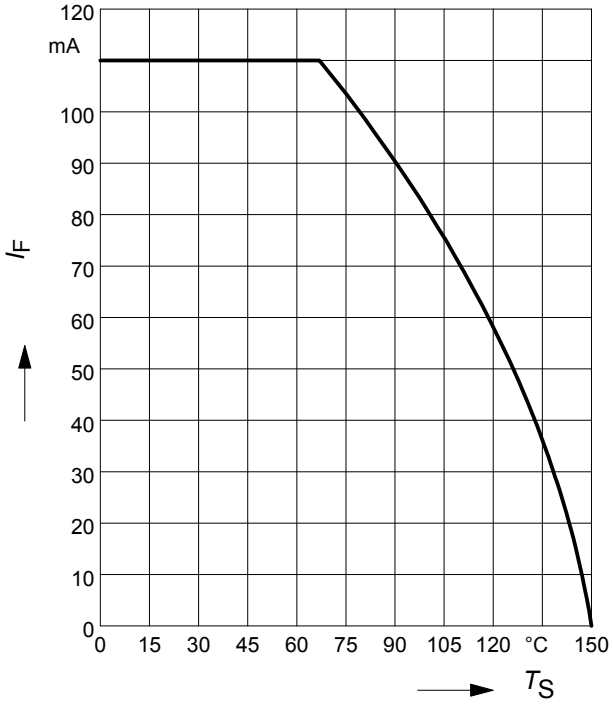
Forward current $I_F = f(T_S)$

BAT15-099



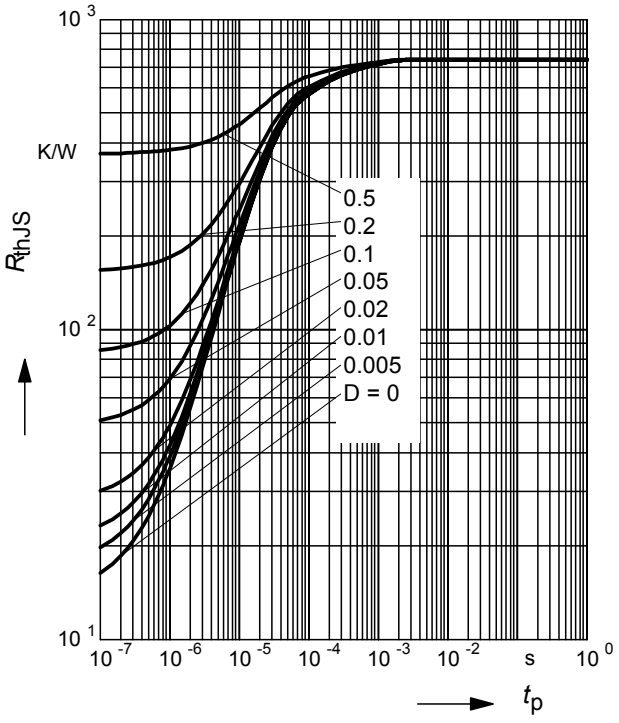
Forward current $I_F = f(T_S)$

BAT15-099R



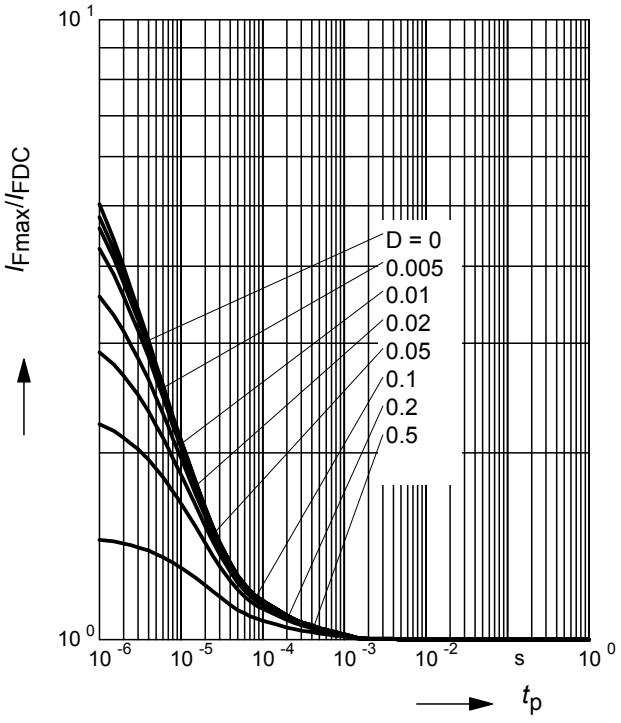
Permissible Puls Load $R_{thJS} = f(t_p)$

BAT15-02LRH, BAT15-099LRH



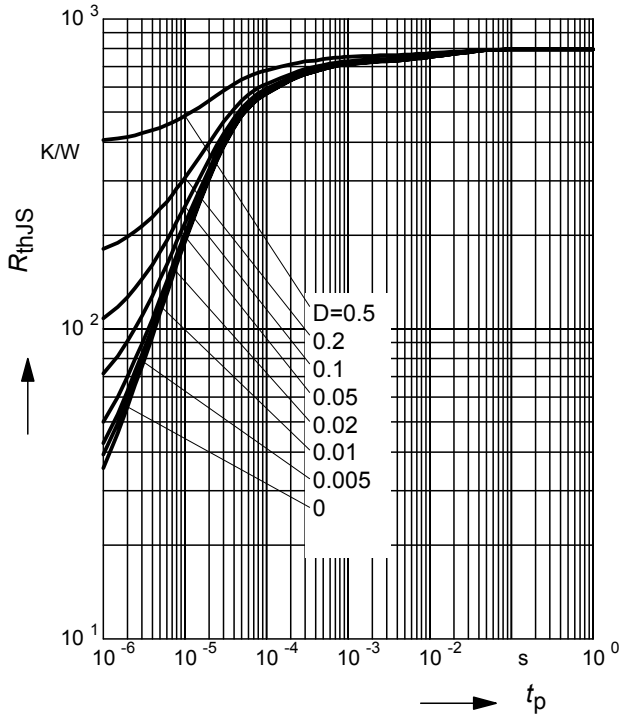
Permissible Pulse Load

$I_{Fmax}/I_{FDC} = f(t_p)$ BAT15-02LRH, BAT15-099LRH



Permissible Puls Load $R_{thJS} = f(t_p)$

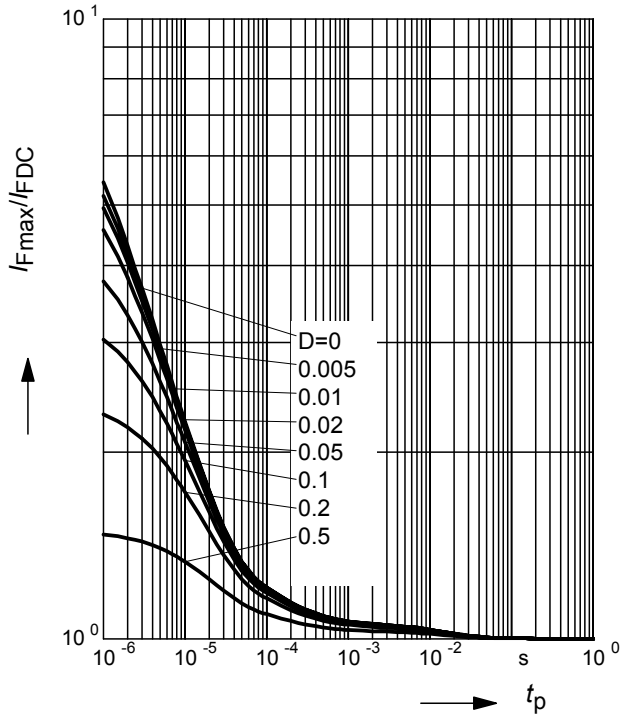
BAT15-03W



Permissible Pulse Load

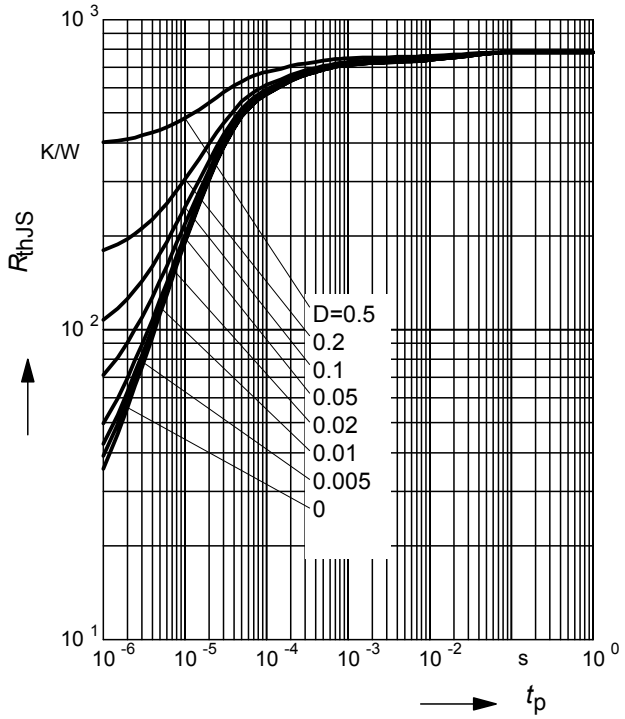
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAT15-03W



Permissible Puls Load $R_{thJS} = f(t_p)$

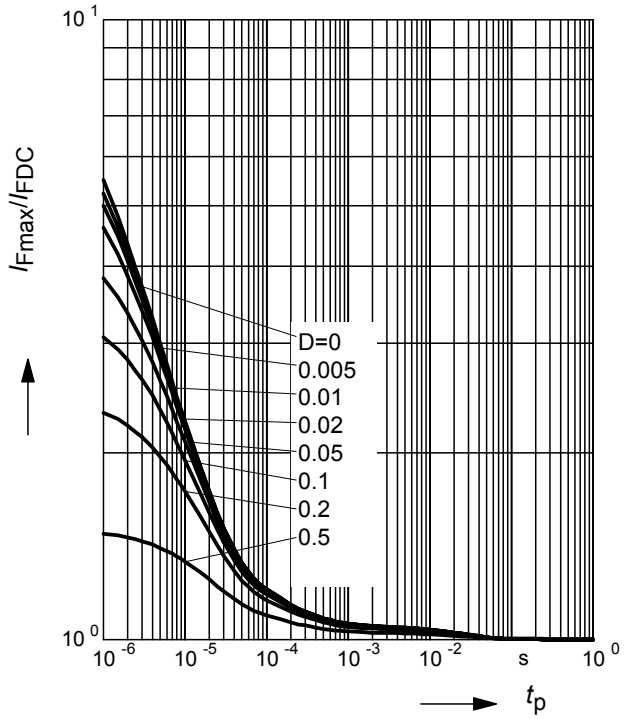
BAT15-04W



Permissible Pulse Load

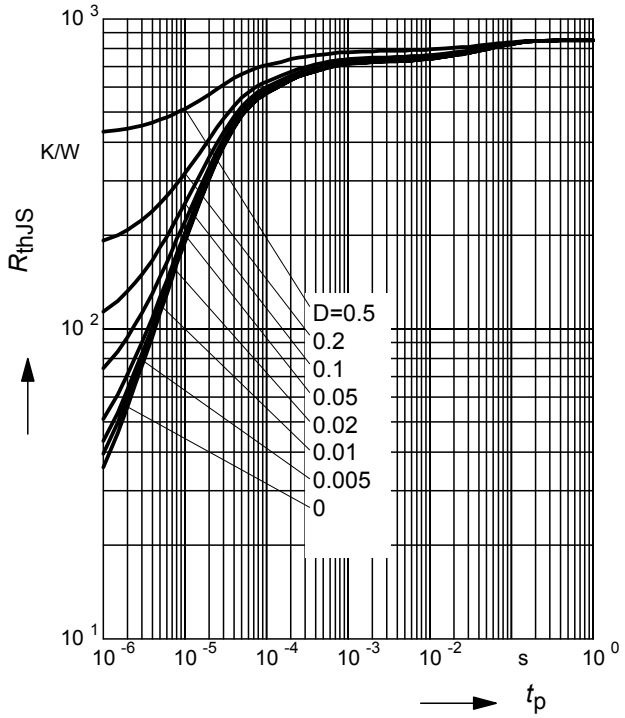
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAT15-04W



Permissible Puls Load $R_{thJS} = f(t_p)$

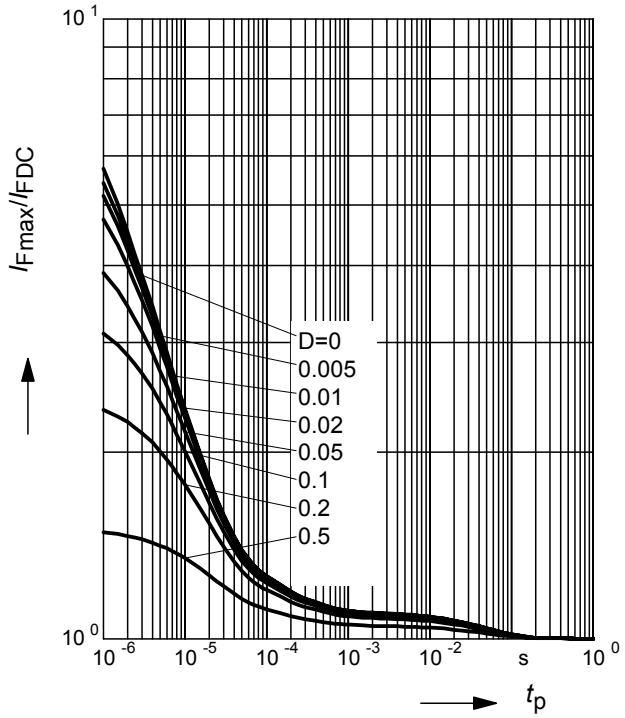
BAT15-05W



Permissible Pulse Load

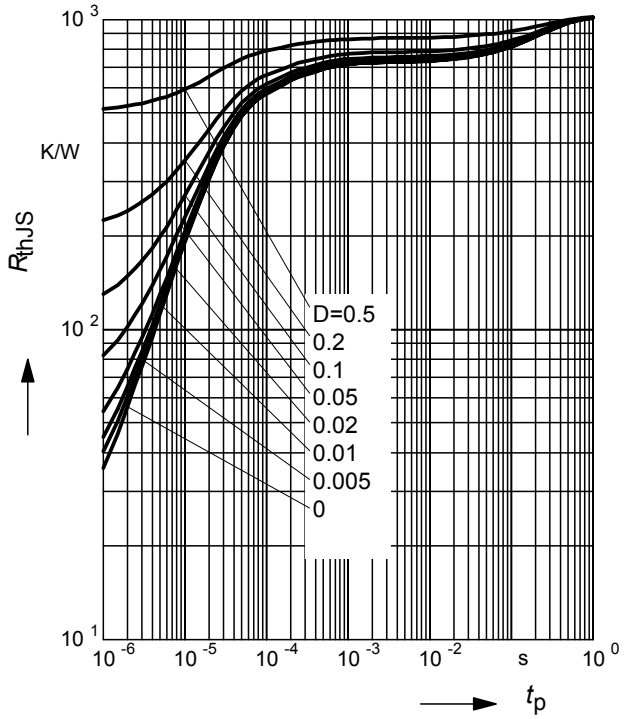
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAT15-05W



Permissible Puls Load $R_{thJS} = f(t_p)$

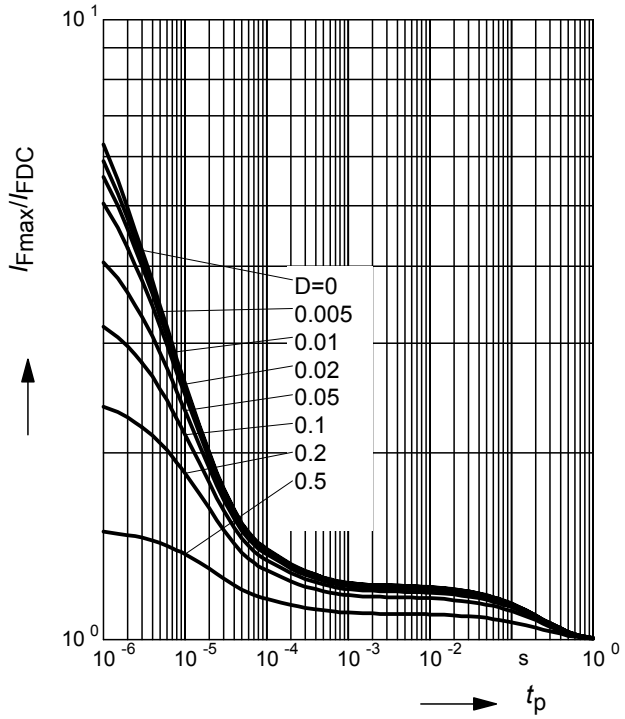
BAT15-099



Permissible Pulse Load

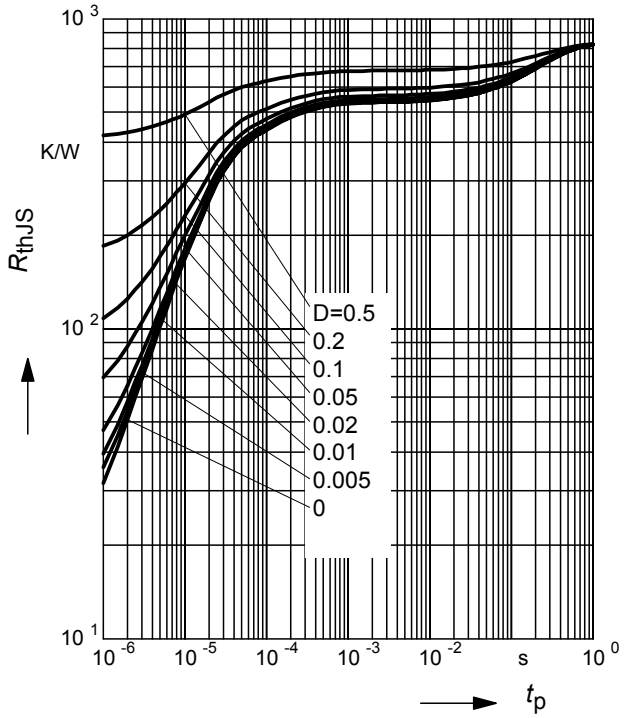
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAT15-099



Permissible Puls Load $R_{thJS} = f(t_p)$

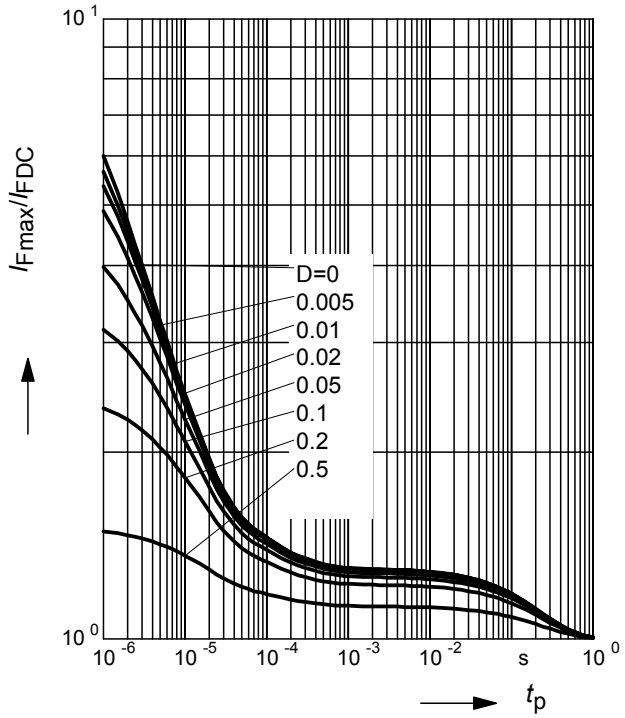
BAT15-099R



Permissible Pulse Load

$I_{Fmax}/I_{FDC} = f(t_p)$

BAT15-099R

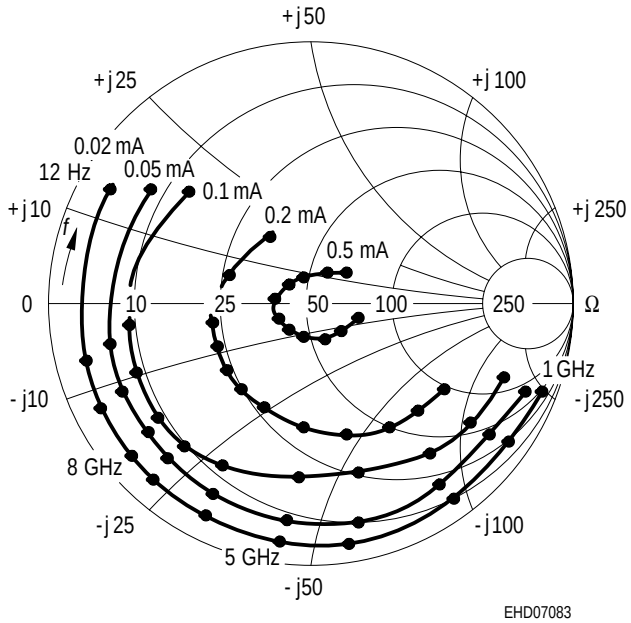


S_{11}-Parameters for BAT15-099

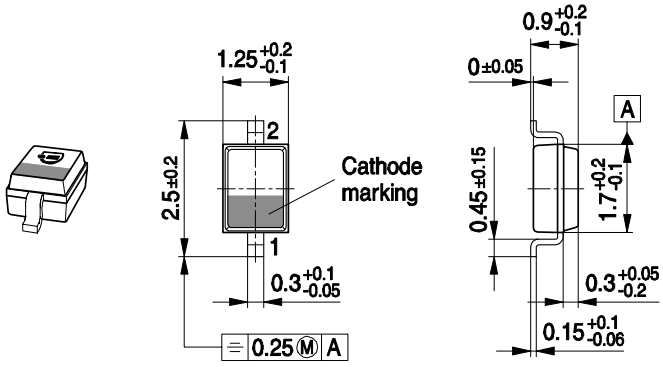
Typical impedance characteristics (with external bias *I* and *Zo* = 50Ω)

f	*I* = 0.02 mA		*I* = 0.05 mA		*I* = 0.1 mA		*I* = 0.2 mA		*I* = 0.5 mA	
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1	0.94	-16.4	0.84	-16.6	0.77	-16.4	0.59	-17.2	0.19	-16.7
2	0.93	-33.8	0.88	-33.8	0.77	-34.5	0.58	-35.2	0.15	-36.1
3	0.92	-53.8	0.86	-54.5	0.75	-54.1	0.58	-56.1	0.13	-64.8
4	0.91	-74.3	0.84	-75.3	0.72	-76.4	0.51	-78.4	0.11	-104.8
5	0.91	-96.6	0.84	-97.6	0.72	-99.1	0.53	-102.3	0.15	-135.7
6	0.91	-115.4	0.84	-116.7	0.73	-118.7	0.53	-122.9	0.18	-160.9
7	0.91	-131	0.84	-132.3	0.73	-134.1	0.54	-138.1	0.2	-168.8
8	0.91	-143	0.84	-144.5	0.73	-146.8	0.55	-150.5	0.81	179.4
9	0.91	-155.6	0.83	-150.2	0.71	-159.7	0.53	-163.9	0.18	179.4
10	0.9	-167.3	0.83	-169.7	0.71	-178.8	0.51	-175.8	0.14	151.2
11	0.89	175.5	0.8	172.6	0.7	170	0.45	164.9	0.09	105.5
12	0.88	175.5	0.76	146.5	0.62	142.8	0.39	134.2	0.14	43.6

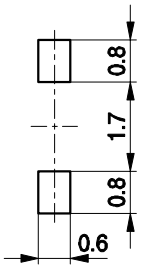
S_{11} = (*f, I*) BAT15-099



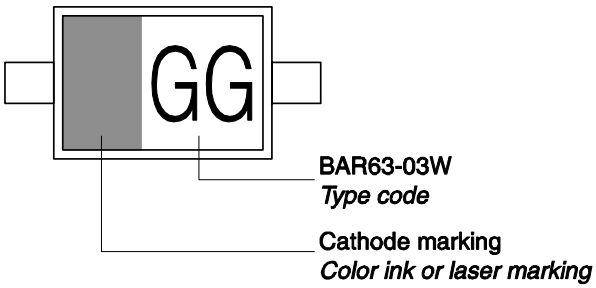
Package Outline



Foot Print

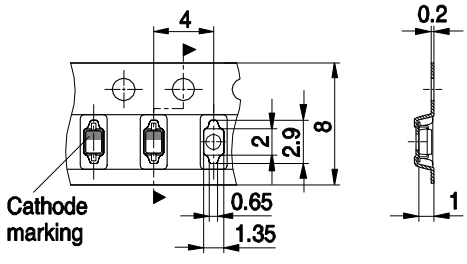


Marking Layout (Example)

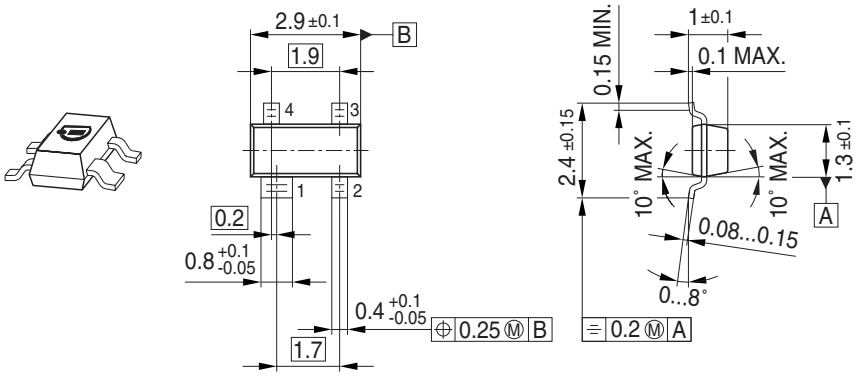


Standard Packing

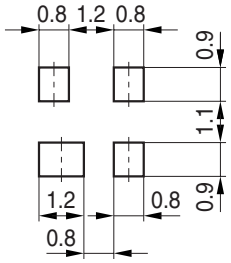
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



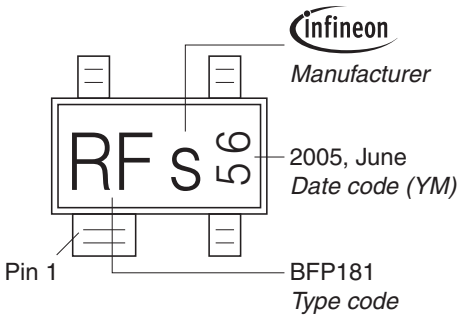
Package Outline



Foot Print

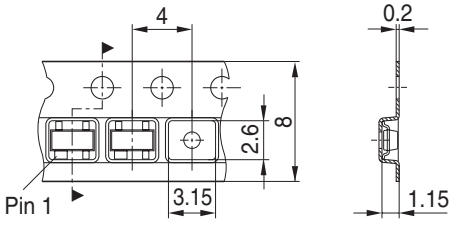


Marking Layout (Example)

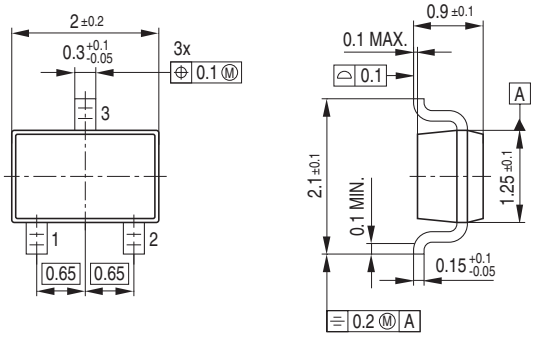


Standard Packing

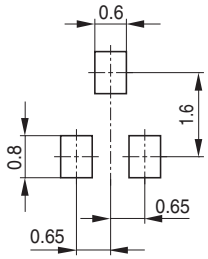
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



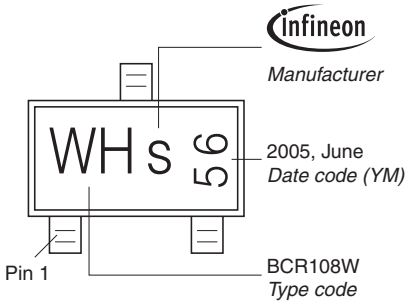
Package Outline



Foot Print

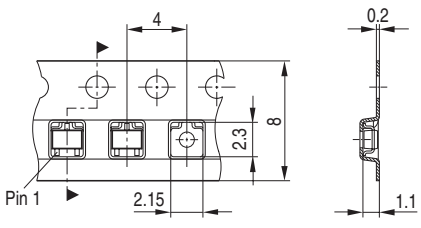


Marking Layout (Example)

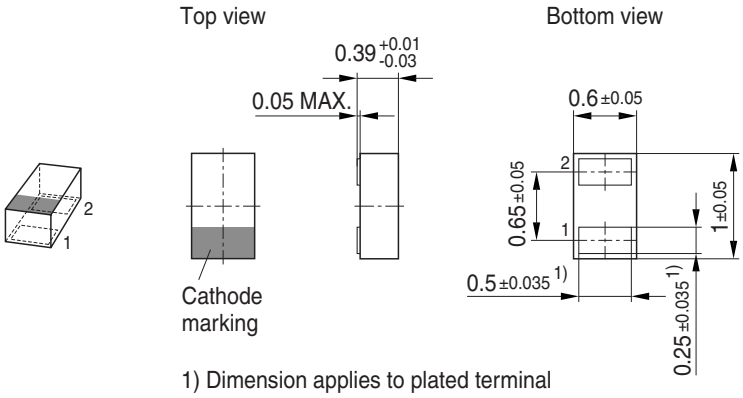


Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



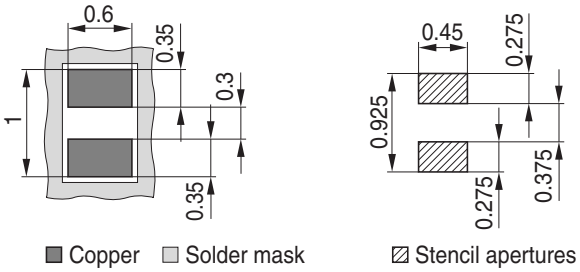
Package Outline



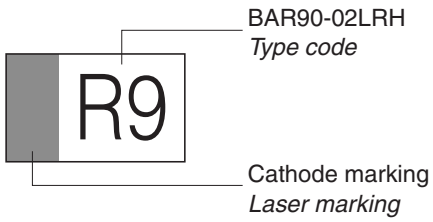
1) Dimension applies to plated terminal

Foot Print

For board assembly information please refer to Infineon website "Packages"

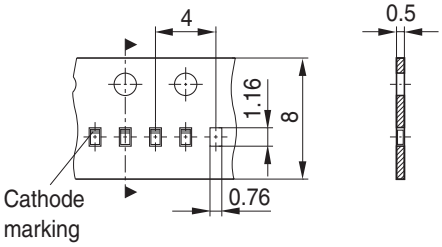


Marking Layout (Example)

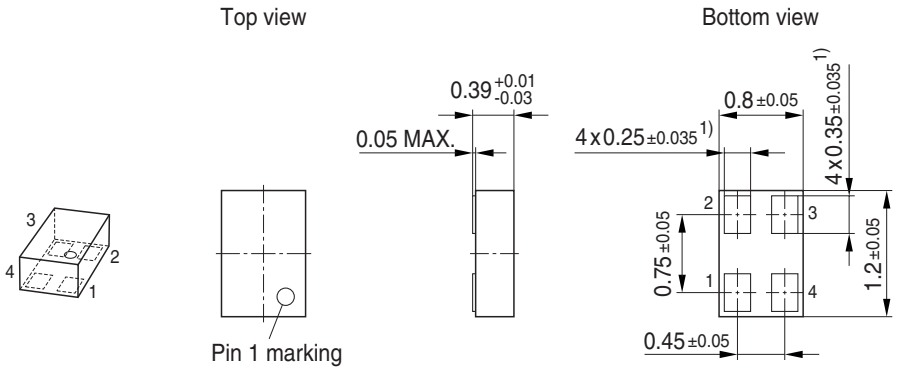


Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel
Reel ø330 mm = 50.000 Pieces/Reel (optional)



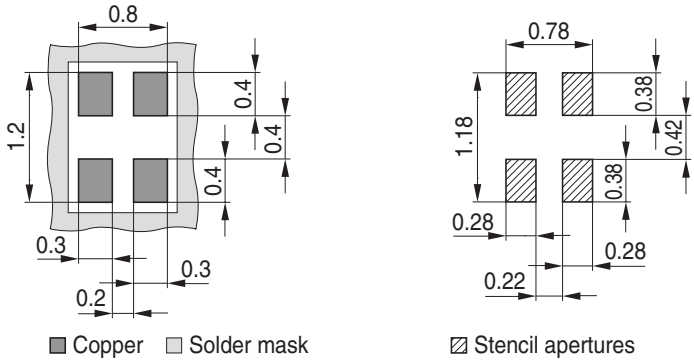
Package Outline



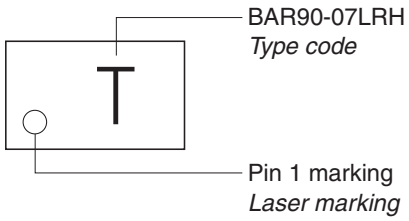
1) Dimension applies to plated terminal

Foot Print

For board assembly information please refer to Infineon website "Packages"

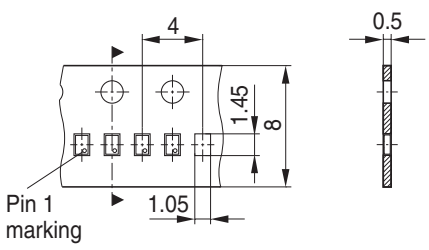


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



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